L Number	Hits	Search Text	DB	Time stamp
1	593620	semiconductor or ic or "integrated circuit" or	USPAT;	2004/10/13
2	145280	microelectronic rins\$3	US-PGPUB USPAT;	16:58
2	143260	11115\$3	USPAT; US-PGPUB	2004/10/13 16:58
3	2796735	surface 2near (bath or liquid)	USPAT;	2004/10/13
•	2/30/33	Surface zhear (bath of liquid)	US-PGPUB	16:59
4	15440	surface with (bath or liquid) with (particles or	USPAT;	2004/10/13
,]	contaminants)	US-PGPUB	16:59
5	815	(semiconductor or ic or "integrated circuit" or	USPAT;	2004/10/13
		microelectronic) and rins\$3 and (surface with	US-PGPUB	17:00
		(bath or liquid) with (particles or contaminants))		
6	422011	semiconductor	USPAT;	2004/10/13
_			US-PGPUB	17:00
7	735	((semiconductor or ic or "integrated circuit" or	USPAT;	2004/10/13
		microelectronic) and rins\$3 and (surface with	US-PGPUB	17:02
		(bath or liquid) with (particles or		
8	34	contaminants))) and semiconductor	LICDAT.	2004/10/12
3	34	rins\$3 with wafer with surface with (bath or liquid) with particles	USPAT; US-PGPUB	2004/10/13 17:53
9	94	valve with (surface with (bath or liquid) with	USPAT;	2004/10/13
		(particles or contaminants))	US-PGPUB	18:27
10	720684	drain or valve	USPAT;	2004/10/13
			US-PGPUB	18:27
11	220236	surface with (bath or liquid or rinsing)	USPAT;	2004/10/13
		, ' '	US-PGPUB	18:28
12	9123	(drain or valve) with (surface with (bath or liquid	USPAT;	2004/10/13
		or rinsing))	US-PGPUB	18:28
13	422011	semiconductor	USPAT;	2004/10/13
			US-PGPUB	18:28
14	1107	((drain or valve) with (surface with (bath or	USPAT;	2004/10/13
15	1429448	liquid or rinsing))) and semiconductor @ad>19980727 @rlad>19980727	US-PGPUB	18:29
13	1429440		USPAT; US-PGPUB	2004/10/13 18:29
16	406	(((drain or valve) with (surface with (bath or	USPAT;	2004/10/13
10	100	liquid or rinsing))) and semiconductor) not	US-PGPUB	18:30
		(@ad>19980727 @rlad>19980727)	00 1 01 02	10.00
17	514037	particles	USPAT;	2004/10/13
			US-PGPUB	18:30
18	145	((drain or valve) with (surface with (bath or	USPAT;	2004/10/13
		liquid or rinsing))) with particles	US-PGPUB	18:31
19	15	semiconductor and (((drain or valve) with	USPAT;	2004/10/13
		(surface with (bath or liquid or rinsing))) with	US-PGPUB	18:31
20	_	particles)	LICDAT	2004/40/42
20	4	(semiconductor and (((drain or valve) with	USPAT;	2004/10/13
		(surface with (bath or liquid or rinsing))) with particles)) not (@ad>19980727	US-PGPUB	18:33
		@rlad>19980727		
21	1545	"rinsing bath" or "rinse bath"	USPAT;	2004/10/13
	13.3	initial battle	US-PGPUB	18:33
22	514037	particles	USPAT;	2004/10/13
	,	<u> </u>	US-PGPUB	18:33
23	2432808	surface	USPAT;	2004/10/13
			US-PGPUB	18:33
24	23	particles with surface with ("rinsing bath" or	USPAT;	2004/10/13
	65076	"rinse bath")	US-PGPUB	18:34
-	65379	438/\$.ccls.	USPAT;	2004/03/31
			US-PGPUB	19:04